

Title (en)

A METHOD OF BRAZING ADJOINING SURFACES OF ELEMENTS

Publication

EP 0055378 A3 19820804 (EN)

Application

EP 81109164 A 19811029

Priority

US 22160680 A 19801231

Abstract (en)

[origin: EP0055378A2] Brazing of metallic elements to an electronic circuit board carrying a plurality of chips requires brazing materials which remain strong at high temperatures used to remove and replace the chips attached by solder balls to the board. According to the present invention flanges and pins (19) are brazed to the board (10) with a gold tin brazing solder (15) which is modified during brazing by addition of a Group IB metal (13) to promote formation of the higher melting point β phase of the solder and a Group VIII metal (14) to drawtin out of the melt by gettering. The melting temperature of the brazing solder is raised substantially during brazing to a value above the melting temperature of the solder balls attached to the chips.

IPC 1-7

B23K 35/30; **B23K 35/02**; **H01L 21/48**

IPC 8 full level

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CPC (source: EP US)

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C-Set (source: EP US)

H01L 2924/00013 + **H01L 2224/29099**

Citation (search report)

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